General Description

The Maxim MX7537/MX7547 contain two 12-bit currentoutput multiplying digital-to-analog converters (DAC) in a single package. Input level shifters, data registers and control logic make microprocessor interfacing straightforward. Operation is from a single +12V to +15V power supply maintaining TTL, 74HC and 5V CMOS logic compatibility.

The MX7547 accepts \overline{CSA} , \overline{CSB} , \overline{WR} control signals and 12 data inputs for DAC selection and full parallel data loading. The MX7537 receives data in 2 bytes, using a right justified 8+4 format. A0, A1, \overline{CS} , \overline{WR} and UPD signals provide full control for DAC selection and data loading.

Each of the DACs in the MX7537/MX7547 provides 4quadrant multiplication capabilities and separate reference input and feedback resistor pins. The MX7537 additionally makes available separate AGND pins for applications where each DAC is biased at a different voltage. Since both DACs are on a single monolithic chip, matching and temperature tracking between them is excellent. Gain error is specified at less than ± 1 LSB, and 12-bit linearity and monotonicity are guaranteed over the full operating temperature ranges.

Maxim's MX7537 and MX7547 are available in narrow 24-lead 0.3" DIP and Wide SO, as well as, 28-pin-lead PLCC packages.

Applications

Automatic Test Equipment Audio Gain Control Motion Control Systems

Wotien Control System

Synchro Applications

Process Control

Digitally Controlled Filters

Features

- Two 12-Bit DACs in One Package
- 0.5% DAC-to-DAC Matching
- Narrow 0.3" DIP, Wide SO, and PLCC Packages
- 4-Quadrant Multiplication
- Low INL and DNL (±1/2 LSB max)
- Gain Accuracy to ±1 LSB max
- Low Gain Tempco (±5ppm/°C max)
- Operates with Single +12V to +15V Supply
- Fast Microprocessor Interface

Ordering Information

PART	TEMP. RANGE	PACKAGE	GAIN ERROR
MX7537JN	0°C to +70°C	24 Plastic DIP	$\pm 6 LSB$
MX7537KN	0°C to +70°C	24 Plastic DIP	$\pm 3 \text{ LSB}$
MX7537LN	0°C to +70°C	24 Plastic DIP	$\pm 1 \text{ LSB}$
MX7537JCWG	0°C to +70°C	24 Wide SO	$\pm 6 LSB$
MX7537KCWG	0°C to +70°C	24 Wide SO	$\pm 3 \text{ LSB}$
MX7537LCWG	0°C to +70°C	24 Wide SO	$\pm 1 \text{ LSB}$
MX7537JP	0°C to +70°C	28 PLCC	$\pm 6 \text{ LSB}$
MX7537KP	0°C to +70°C	28 PLCC	$\pm 3 \text{ LSB}$
MX7537LP	0°C to +70°C	28 PLCC	$\pm 1 \text{ LSB}$
MX7537J/D	0°C to +70°C	Dice	$\pm 6 \text{ LSB}$
MX7537AQ	-25°C to +85°C	24 CERDIP	±6 LSB
MX7537BQ	-25°C to +85°C	24 CERDIP	±3 LSB
MX7537CQ	-25°C to +85°C	24 CERDIP	$\pm 1 \text{ LSB}$

(Ordering Information continued on page 15.)

Pin Configurations



///XI//

_Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

V _{DD} to DGND
V _{REFA} , V _{REFB} to AGND ±25V
V _{RFBA} , V _{RFBB} to AGND ±25V
Digital Input Voltage to DGND0.3V, V _{DD} +0.3V
I _{OUTA} , I _{OUTB} Voltage to DGND0.3V, V _{DD} +0.3V
AGND to DGND
Power Dissipation (Any Package)
To +75°C 450mW
Derates above +75°C 6mW/°C

Operating Temperature Range
MX7537J/K/L, MX7547J/K/L 0°C to +70°C
MX7537A/B/C, MX7547A/B/C25°C to +85°C
MX7537JE/KE/LE, MX7547JE/KE/LE40°C to +85°C
MX7537S/T/Q, MX7547S/T/Q55°C to +125°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10 sec.) +300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{DD} = +12V \text{ to } +15V, \pm 10\%, V_{REFA} = V_{REFB} = +10V, V_{AGND} = V_{DGND} = V_{IOUTA} = V_{IOUTB} = 0V$, output amplifiers are MAX400s, $T_A = T_{MIN}$ to T_{MAX} unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				MIN	TYP	MAX	UNITS	
STATIC PERFORMAN	CE	-								
Resolution	N					12			Bits	
Relative Accuracy	INL			мх	MX75X7J/A/Q 75X7K/L/B/C/T/U			±1 ±½	LSB	
Differential Nonlinearity	DNL	All grades guarar	nteed monotonic	over t	emperature.			±1	LSB	
Gain Error	FSE	Measured using R _{FBA} , R _{FBB} . Both DAC registers loaded with all 1s. MX75X7L/C MX75X7U MX75X7K/B/T MX75X7J/A/S				±1 ±2 ±3 ±6	LSB			
Gain Tempco ∆Gain/∆Temperature (Note 1)	TCFS				±1	±5	ppm/°C			
1 1		DAC register		All	T _A = +25°C			±10		
I _{OUTA} , I _{OUTB} Leakage Current	ILKG	all 0s.	loaded with all 0s. MX75X7J/K/L/A/B MX75X7S/T		$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}			±150 ±250		
REFERENCE INPUT			-							
V _{REFA} , V _{REFB} Input Resistance	R _{REF}					9	14	20	kΩ	
V _{REFA} , V _{REFB} Input Resistance Match	ΔR_{REF}			M	MX75X7L/C/U (75X7J/K/A/B/S/T		±0.5 ±0.5	±1 ±3	% %	
DIGITAL INPUTS										
Input High Voltage	VIH					2.4			V	
Input Low Voltage	V _{IL}							0.8	V	
Input Current	I _{IN}	$V_{IN} = 0V \text{ or } V_{DD}$			$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to T_{MAX}			±1 ±10	μΑ	
Input Capacitance (Note 1)	C _{IN}							10	pF	

ELECTRICAL CHARACTERISTICS (continued) $(V_{DD} = +12V \text{ to } +15V, \pm 10\%, V_{REFA} = V_{REFB} = +10V, V_{AGND} = V_{DGND} = V_{IOUTA} = V_{IOUTB} = 0V$, output amplifiers are MAX400s, $T_A = T_{MIN}$ to T_{MAX} unless otherwise noted.)

PARAMETER	SYMBOL		CONDITIONS		MIN	TYP	MAX	UNITS
POWER SUPPLY								
Current Matterna		Operating Range).		10.8		16.5	v
Supply Voltage	V _{DD}	Functional with o	degraded specifications.			5.0		v
Supply Current	I _{DD}						2	mA
DYNAMIC PERFORM	ANCE (Note	2)						
Current Settling Time	t _s		To $\pm \frac{1}{2}$ LSB. I_{OUT} load is $100\Omega \parallel 13$ pF. DAC output measured from rising $T_A = +25^{\circ}$ C edge of WR.				1.5	μs
Digital-to-Analog Glitch Impulse		Measured with V 100 $\Omega \parallel$ 13pF. DA 1s and all 0s.	Measured with $V_{REFA} = V_{REFB} = 0V$. I_{OUT} load is 100 $\Omega \parallel$ 13pF. DAC registers alternately loaded with all 1s and all 0s.					nV-s
AC Feedthrough	gh FTE	DAC registers	V _{REFA} = 20Vp-p 10kHz sine wave, V _{REFB} = 0V	V _{REFA} to I _{OUTA}			-70	
		loaded with all 0s.	V _{REFB} =20Vp-p 10kHz sine wave, V _{REFA} = 0V	V_{REFB} to I_{OUTB}			-70	dB
Power Supply Rejection ∆Gain/∆V _{DD}	PSR	$\Delta V_{DD} = V_{DD} \text{ max} - V_{DD} \text{ min.}$					±0.001	%/%
Output Capacitance (I _{OUTA} , I _{OUTB})	C _{OUT}		oaded with all 0s. oaded with all 1s.				70 140	pF
Channel-to-Channel		V _{REFA} = 20Vp-p V _{REFB} = 0V	10kHz sine wave,	V_{REFA} to I_{OUTB}		-84		
Isolation		$V_{\text{REFB}} = 20Vp-p \ 10kHz \ sine \ wave, V_{\text{REFB}} = 0V$ $V_{\text{REFB}} \ to \ I_{\text{OUTA}}$			-84		dB	
Digital Crosstalk		Measured for digital inputs changed from all 0s to all 1s. $I_{OUTA},\ I_{OUTB}$ load is 1000 \parallel 13pF.				7		nV-s
Total Harmonic Distortion		V _{IN} = 6V _{RMS} , 1kHz. Both DACs loaded with all 1s.				-82		dB
Output Noise Voltage Density (10Hz to 100kHz)		Measured betwe	en R _{FBA} and I _{OUTA} or R	FBB and I _{OUTB} .	4	25		nV//Hz

Note 1: Guaranteed by design.

Note 2: These characteristics are for design guidance only and are not subject to test.

TIMING CHARACTERISTICS—AD7537

(V_{DD} = +10.8V to +16.5V. See Figure 2 for timing diagram.)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS	
		All	$T_{A} = +25^{\circ}C$	20				
Address Valid to Write Setup Time	t ₁	MX7537J/K/L/A/B/C MX7537S/T/U	$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}	20 30			ns	
		All	$T_A = +25^{\circ}C$	20				
Address Valid to Write Hold Time	t ₂	MX7537J/K/L/A/B/C MX7537S/T/U	$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}	20 25			ns	
Data Setup Time	t ₃	All	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to T_{MAX}	60 80			ns	
Data Hold Time	t ₄			25			ns	
Chip Select or Update to Write Setup Time	t ₅			0			ns	
Chip Select or Update to Write Hold Time	t ₆			0			ns	
		All	$T_A = +25^{\circ}C$	80				
Write Pulse Width	t ₇	MX7537J/K/L/A/B/C MX7537S/T/U	$T_{A} = T_{MIN} \text{ to } T_{MAX}$ $T_{A} = T_{MIN} \text{ to } T_{MAX}$	80 100			ns	
		All	$T_A = +25^{\circ}C$	80				
Clear Pulse Width	t ₈	MX7537J/K/L/A/B/C MX7537S/T/U	$T_{A} = T_{MIN} \text{ to } T_{MAX}$ $T_{A} = T_{MIN} \text{ to } T_{MAX}$	80 100			ns	

TIMING CHARACTERISTICS—AD7547

(V_{DD} = +10.8V to +16.5V. See Figure 3 for timing diagram.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
		All	T _A = +25°C	60			
Data Setup Time	t ₁	MX7547J/K/L/A/B/C MX7547S/T/U	$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}	60 80			ns
Data Hold Time	t ₂			25			ns
	t ₃	All	$T_A = +25^{\circ}C$	80			ns
Chip Select to Write Setup Time		MX7547J/K/L/A/B/C MX7547S/T/U	$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}	80 100			
Chip Select to Write Hold Time	t ₄			0			ns
Write Pulse Width		All	$T_A = +25^{\circ}C$	80			ns
	t ₅	MX7547J/K/L/A/B/C MX7547S/T/U	$T_A = T_{MIN}$ to T_{MAX} $T_A = T_{MIN}$ to T_{MAX}	80 100			

Functional Diagrams

MX7537/MX7547



Pin Configurations (continued)



/VI/IXI/VI

Pin Descriptions

Table 1. MX7537 Truth Table

		MX7537
PIN	NAME	FUNCTION
1	AGNDA	Analog ground for DAC A
2	IOUTA	Current output for DAC A
3	R _{FBA}	Feedback resistor for DAC A
4	V _{REFA}	Reference input for DAC A
5	CS	Chip select input. Active low.
6-14	DB0-DB7	Data inputs
12	DGND	Digital ground
15	A0	Address input
16	A1	Address input
17	CLR	Clear input. Active low. Clears all registers.
18	WR	Write input. Active low.
19	UPD	Update input. Active low. Updates DAC registers from input registers.
20	V _{DD}	Power supply input. +12V to +15V with \pm 10% tolerance.
21	V _{REFB}	Reference input for DAC B
22	R _{FBB}	Feedback resistor for DAC B
23	I _{OUTB}	Current output for DAC B
24	AGNDB	Analog ground for DAC B

CLR	UPD	\overline{cs}	WR	A1	A0	FUNCTION
1	1	1	Х	х	х	No Data Transfer
1	1	Х	1	х	X	No Data Transfer
0	Х	Х	Х	х	X	All Registers Cleared
1	1	0	0	0	0	DAC A LS Input Register Loaded with DB7-DB0.
1	1	0	0	0	1	DAC A MS Input Register Loaded with DB3-DB0.
1	1	0	0	1	0	DAC B LS Input Register Loaded with DB7-DB0.
1	1	0	0	1	1	DAC B MS Input Register Loaded with DB3-DB0.
1	0	1	0	x	x	DAC A, DAC B Registers Updated Simultaneously from Input Registers. Input Registers Not Changed.
1	0	0	0	x	x	DAC A, DAC B Registers are Transparent. Input Registers Loaded as Shown Above.

Note: X = Don't Care

Table 2. MX7547 Truth Table

		MX7547
PIN	NAME	FUNCTION
1	AGND	Analog ground
2	IOUTA	Current output for DAC A
3	R _{FBA}	Feedback resistor for DAC A
4	VREFA	Reference input for DAC A
5	CSA	Chip select input for DAC A. Active low.
6-18	DB0-DB11	Data inputs. DB0(LSB) to DB11(MSB)
12	DGND	Digital ground
19	WR	Write input. Active low.
20	CSB	Chip select input for DAC B. Active low.
21	V _{DD}	Power supply input. +12V to +15V with \pm 10% tolerance.
22	V _{REFB}	Reference input for DAC B
23	R _{FBB}	Feedback resistor for DAC B
24	I _{OUTB}	Current output for DAC B

CSA	CSB	WR	FUNCTION
Х	X	1	No Data Transfer
1	1	Х	No Data Transfer
	_ _	0	A Rising Edge on CSA or CSB Transfers Data to the Respective DAC.
0	1	1	DAC A Register Loaded from Data Bus.
1	0	1	DAC B Register Loaded from Data Bus.
0	0	Ţ	DAC A and DAC B Registers Loaded from Data Bus.

Notes:

X = Don't care.
WR Input is edge-triggered.

Detailed Description D/A Converter

The basic MX7537/MX7547 circuit includes two identical DACs with laser trimmed, thin-film resistor (R-2R) arrays and NMOS current switches, as shown in Figure 1. Binary weighted currents switch to either IOUT or GND depending on the status of each input data bit. Although the currents at IOUT and GND depend on the digital input code, the sum of the two output currents are always equal to the input current at VREF.

Either current output can be converted to a voltage by adding an external output amplifier (Figures 4, 5). The V_{REF} input accepts a wide range of signals, including fixed and time varying voltage or current inputs. If a current source is used for the reference input, a low tempco external resistor should be used for R_{FB} to minimize gain variation with temperature.



Figure 1. Simplified Circuit Diagram for DAC

The internal feedback resistor, R_{FB} , is compensated with an NMOS switch that matches the NMOS switches used in the R-2R array. This results in excellent supply rejection and gain temperature coefficient.

The I_{OUT} pin output capacitance, C_{OUT} is code dependent and is typically 40pF with all switches connected to GND and 100pF with all switches to IOUT.

Digital Circuit

The input buffer inverters of the MX7537/MX7547 act as level shifters converting TTL levels into CMOS logic levels. Logic inputs are TTL, 74HC, and +5V CMOS compatible (0.8V and 2.4V) at V_{DD} = +12V to +15V. DAC supply current can be reduced below specified levels by keeping digital input voltages as close to the logic supply and ground as possible (as with CMOS logic levels). All logic inputs are designed to withstand ESD voltages of over 5,000V.

MX7537 Interface

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Figure 2 shows the timing diagram for the MX7537. A1 and A0 select the most-significant (MS) or the leastsignificant (LS) input registers for DAC A or DAC B (Table 1). When loading the MS register, DB3 is the MSB of the 12-bit data input. Similarly, when the LS register is loaded, DB0 is the LSB. Data is loaded into the DAC when CS and WR both go low. CLR and UPD must be kept high while the data is loaded. When CLR is low, all registers are cleared without regard to the state of other control signals. When UPD and WR are low, the DAC registers are updated simultaneously from the input registers. When UPD, CS and WR are low, the DAC registers are transparent and load the



Figure 2. Timing Diagram for MX7537

data inputs immediately, as selected by the address inputs. Figure 17 shows the control logic equivalent circuit for the MX7537.

MX7547 Interface

Figure 3 shows the timing diagram for the MX7547. Data is loaded into the DAC A register on the rising edge of WR while CSA is low. Similarly, DAC B register is loaded on the rising edge of WR while CSB is low (Table 2).





Figure 4A. MX7537 Unipolar Binary Operation

Figure 3. Timing Diagram for MX7547

Circuit Configurations Unipolar Operation

Basic applications of the MX7537/MX7547 are shown in Figure 4. These circuits are used for unipolar operation or 2-quadrant multiplication. The code table for this mode is given in Table 3. Note that the polarity of the output is the inverse of the reference voltage, $V_{\rm IN}.$

Table 3. Bina	ry Code for	Unipolar	Circuit
---------------	-------------	----------	---------

BINARY NUMBER MSB LSB			VOUTA OF VOUTB		
1111	1111	1111	$-V_{1N}\left(\frac{4095}{4096}\right)$		
1000	0000	0000	$-V_{IN}\left(\frac{2048}{4096}\right) = -1/2 V_{IN}$		
0000	0000	0001	$-V_{IN}\left(\frac{1}{4096}\right)$		
0000	0000	0000	0V		



Figure 4B. MX7547 Unipolar Binary Operation

M/X//VI

To adjust the circuits of Figure 4, correct the zero error, if necessary, by loading the appropriate DAC with all 0's code and adjusting the amplifier offset so that $V_{OUT} = 0V$. Next, correct the full scale error by loading the DAC with all 1s and adjust resistors R1 (or R3) so that $V_{OUT} = -V_{IN}(4095/4096)$.

In many applications, gain adjustment is not necessary if the untrimmed gain accuracy of the DAC is sufficient, or if the gain is trimmed at the voltage reference source. In these cases, resistors R1, R2, R3 and R4 can be omitted. When trimming is used and the DAC is operated over a wide temperature range, then low tempco (<300ppm/°C) resistors should be used for these resistors.

The capacitors C1 and C2 provide phase compensation and reduce overshoot and ringing when fast amplifiers are used at the output of the DAC. Single or dual op amps can be used in this application.

Bipolar Operation

Figure 5 shows the MX7537/MX7547 operating in the bipolar, or 4-quadrant multiplying mode. These circuits require an additional amplifier and three matched resistors (R3, R4 and R5) for each DAC. The resistors must be of the same material (preferably metal film or wire-wound) for best temperature tracking characteristics (<15ppm/°C), and should match to 0.01% for 12-bit performance. Output code is offset binary and

is listed in Table 4. In multiplying applications, the MSB determines output polarity while the lower eleven bits control amplitude. The MSB can be inverted in software using an exclusive-OR instruction to make the MX7537/MX7547 work with 2's complement coding. Table 5 shows the code relationships to output voltage for 2's complement operation.

BINARY NUMBER MSB LSB			ANALOG OUTPUT	
1111	1111	1111	$+V_{IN}\left(\frac{2047}{2048}\right)$	
1000	0000	0001	$+V_{IN}\left(\frac{1}{2048}\right)$	
1000	0000	0000	0V	
0111	1111	1111	$-V_{IN}\left(\frac{1}{2048}\right)$	
0000	0000	0000	$-V_{IN}\left(\frac{2048}{2048}\right) = -V_{IN}$	





Figure 5A. MX7537 Bipolar Operation (Offset Binary Coding) /VI/IXI/VI

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Figure 5B. MX7547 Bipolar Operation (Offset Binary Coding)

DIG	ITAL INF	TIIT	
MSB		LSB	ANALOG OUTPUT
0111	1111	1111	+VIN (2047)
0000	0000	0001	$+V_{IN}\left(\frac{1}{2048}\right)$
0000	0000	0000	0
1111	1111	1111	$-V_{IN}\left(\frac{1}{2048}\right)$
1000	0000	0000	$-V_{IN}\left(\frac{2048}{2048}\right)$

Table	5	2'e	Comn	lement	Code	Table
lable	э.	23	Comp	lement	Coue	able

To adjust the bipolar circuit, load the DAC with a code of 1000 0000 0000 and trim R1 (or R3) for V_{OUT} = 0V. With R1 and R2 (or R3 and R4) omitted, an alternative zero trim is to adjust the ratios of R5 and R6 (or R8

and R10) for V_{QUT} = 0V. Full scale can be trimmed by loading the DAC with all 0s or all 1s and adjusting the amplitude of V_{REF}, or varying R5 (or R8) until the desired positive or negative output is obtained. In many applications, gain adjustment will not be necessary, especially when using parts with \pm 1LSB guaranteed maximum gain error. If R1, R2 (or R3, R4) are omitted, then ratio matched 0.01% resistors must be used at R5, R6 and R7 (R8, R9 and R10) for gain error performance to the data sheet specifications. In any case, if the DAC is operated over a wide temperature range, then low tempco (<300ppm/°C) resistors of the same material will provide best performance.

Single Supply Applications

The MX7537/MX7547 can be conveniently used in single supply operation with AGND biased at any voltage between DGND and V_{DD} . Figure 6 shows an MX7547 application which outputs +5V to +10V by biasing AGND at +5V with respect to DGND. The transfer function for each channel is:

$$V_{OUT} = +5V (1 + R_{FB}/R_{EQ})$$

where $R_{EQ} = \infty$ and $V_{OUT} = +5V$ with all 0s loaded into the DAC, and $R_{EQ} = R_{FB}$ and $V_{OUT} = +10V$ with all 1s in the DAC.

The MX7537 provides separate AGND pins for DAC A and DAC B which allow the two DACs to be biased at different voltages. In Figure 7, DAC A is connected as a programmable attenuator with AGNDA at DGND. DAC B has a +5V bias at AGNDB, resulting in an output range of +5V to +10V for DAC B.

Figure 8 shows a voltage output DAC connection, where I_{OUT} is connected to the reference voltage source (V_{IN}) and AGND is tied to DGND. This is known as "voltage mode" operation. The DAC output now appears at the V_{REF} pin which has a constant output impedance equal to the reference input resistance (typically 11k Ω). R_{FB} is not used in this mode.

Two advantages of the voltage mode operation are single supply operation and that a negative reference is not required for a positive output. Limitations are that the reference input (I_{OUT}) must be positive and less than 2.5V when V_{DD} is 15V. If the reference voltage is greater than 2.5V or V_{DD} is reduced, resistance mismatches in the DAC's internal NMOS switches result in degraded integral (INL) and differential nonlinearity (DNL). For optimum performance, V_{IN} must stay between 0V and 2.5V, and a buffer amplifier should be used at the DAC outputs and the inputs. Figure 9 shows how the differential linearity is affected by increasing V_{IN} .

The unipolar and bipolar circuits in Figures 4 and 5 can all be converted to voltage output mode.



Figure 6. MX7547 Single Supply Operation



Figure 7. MX7537 DACs Used in Different Modes



Figure 8. MX7547 Operated in Single Supply, Voltage Switching Mode



Figure 9. Differential Nonlinearity vs. Reference Voltage for Circuit of Figure 8. V_{DD} = 15V. Shaded Area Shows Range of Values of Differential Nonlinearity that Typically Occurs for L, C and U Grades.

Microprocessor Interface MX7537

The MX7537 2-byte interface simplifies the connection to 8-bit microprocessors (μ P). Figures 10 and 11 show interface connections to the MC6809 and MC68008. Figure 12 shows how multiple MX7537s can be used in a μ P system by tying all the UPD lines together and controlling these with a single address decoder output. Although this application uses a Z80, any other 8-bit μ P can be as easily used.

MX7547

The 12-bit parallel interface circuit of the MX7547 simplifies the interface to 16-bit μ Ps. Figures 13 and 14 show 8086 and 68000 interfaces. Possibility of loading invalid data to the DAC is avoided, since the rising edge of the WR signal is used to load the data into the DAC.

Application Information Output Amplifier Offset

For best linearity, I_{OUT} and AGND should be terminated at exactly 0V. In most applications I_{OUT} is connected to the summing junction of an inverting op amp. The input offset voltage of the amplifier can degrade the linearity of the DAC by causing I_{OUT} to be terminated to a non-zero voltage. The resulting error is:

Error Voltage = V_{OS} (1 + R_{FB}/R_O)

where V_{OS} is the op amp's offset voltage and R_O is the output resistance of the DAC. R_O is a function of the digital input code, and varies from approximately $11 k\Omega$ to $33 k\Omega$. The error voltage range is then typically $4/3V_{OS}$ to $2V_{OS}$, a change of $2/3V_{OS}$. An amplifier with 3mV of offset will, therefore, degrade the linearity by 2mV, almost a full LSB with a 10V reference voltage. For best linearity, a low-offset amplifier such as the MAX400 should be used, or the amplifier offset must be trimmed to zero. A good rule of thumb is V_{OS} should be no more than 1/10LSB.

The output amplifier input bias current (I_B) can also limit performance since $I_B \times R_{FB}$ generates an offset error. I_B should, therefore, be much less than the DAC output current for 1LSB, typically 250nA with V_{REF} = 10V. One tenth of this value, 25nA, is recommended. Offset and linearity can also be impaired if the output amplifier noninverting input is grounded through a "bias current compensation resistor." This resistor adds to the offset at this pin and should not be used. Best performance is obtained when the noninverting input is directly connected to ground.

Dynamic Considerations

In static or DC applications, the AC characteristics of the output amplifier are not critical. In higher speed applications, where either the reference input is an AC signal or the DAC output must quickly settle to a new programmed value, the AC parameters of the output op amp must be considered.

Another error source in dynamic applications is parasitic coupling of signal from the V_{REF} pin to I_{OUT}. This normally is a function of board layout and lead-tolead package capacitance. Noise signals can also be injected into the DAC outputs when the digital inputs are switched. This digital feedthrough is usually dependent on circuit board layout and on-chip capacitive coupling. Layout induced feedthrough can be minimized with guard traces between the digital input, V_{REF}, and I_{OUT} pins. Suggested PC board layouts that minimize the parasitic signal feedthrough from V_{REFA} and V_{REFB} to the DAC outputs in multiplying applications are shown in Figures 15 and 16.

Compensation

A compensation capacitor, C1 (C2), may be required when the DAC is used with a high speed output amplifier. The purpose of the capacitor is to cancel the pole formed by the DAC output capacitance, C_{OUT} , and the internal feedback resistor, R_{FB} . Its value depends on the type of op amp used but typically ranges from 10pF to 33pF. Too small a value causes output ringing while excess capacitance over-damps the output. The size of C1 (C2) can be minimized and the output voltage settling time improved by keeping the circuit board trace and stray capacitance at I_{OUT} as low as possible.



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Figure 10. MX7537 — MC6809 Interface

Figure 11. MX7537 — MC68008 Interface



Figure 12. Expanded MX7537 System

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Figure 13. MX7547 — MC68000 Interface



Figure 14. MX7547 — 8086 Interface

Grounding and Bypassing

Since I_{OUT} and the noninverting input of the output amplifier are sensitive to offset voltages, nodes that are to be grounded should be connected directly to a "single point" ground through a separate, low resistance (less than 0.2 Ω) connection. The current at I_{OUT} and AGND varies with input code, creating a code dependent error if these terminals are connected to ground (or a "virtual ground") through a resistive path.



Figure 15. Suggested Layout for MX7537 Circuit of Figure 4A



Figure 16. Suggested Layout for MX7547 Circuit of Figure 4B

A 1 μ F bypass capacitor, in parallel with a 0.01 μ F ceramic capacitor, should be connected across V_{DD} and DGND as close to the device pins as possible.

The MX7537/MX7547 have high impedance digital inputs. To minimize noise pick-up, they should be tied to either V_{DD} or DGND when not used. It is good practice to connect active inputs to V_{DD} or DGND through high valued resistors (1M Ω) to prevent static charge accumulation if the pins are left floating, such as when a circuit card is left unconnected.



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Figure 17. MX7537 Control Logic Equivalent Circuit



Ordering Information (continued)

Chip Topographies



MX7547



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)



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